

Description

The HD6957 uses advanced trench technology to provide excellent $R_{\text{DS(ON)}}$, low gate charge and operation with gate voltages as low as 4.5V. This device is suitable for use as a Battery protection or in other Switching application.



TO252-2L

General Features

 $V_{DS} = -60V, I_{D} = -30A$

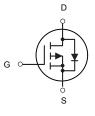
 $R_{DS(ON)} < 33m\Omega$ @ V_{GS} =-10V

Application

PWM applications

Load switch

Power management



P-Channel MOSFET

Package Marking and Ordering Information

Product ID	Pack	Marking	Qty(PCS)
HD6957	TO252-2L	HD6957 XXX YYYY	2500

ABSOLUTE MAXIMUM RATINGS(TA=25°C unless otherwise noted)

Symbol	Parameter	Limit	Unit		
V _{DS}	Drain-Source Voltage (Vcs=0V)	-60	V		
V _G S	Gate-Source Voltage (V _{DS} =0V)	-Source Voltage (V _{DS} =0V) ±20			
	Drain Current-Continuous(Tc=25℃)	-30	Α		
l _D	Drain Current-Continuous(Tc=100°C)	-25.5	А		
IDM (pluse)	Drain Current-Continuous@ Current-Pulsed (Note 1)	-144	А		
D.	Maximum Power Dissipation(T _C =25 ℃)	79	W		
P _D	Maximum Power Dissipation(T _C =100℃)	39.5	W		
Eas	Avalanche energy (Note 2)	196	mJ		
TJ, TSTG	Operating Junction and Storage Temperature Range	-55 To 175	${\mathbb C}$		



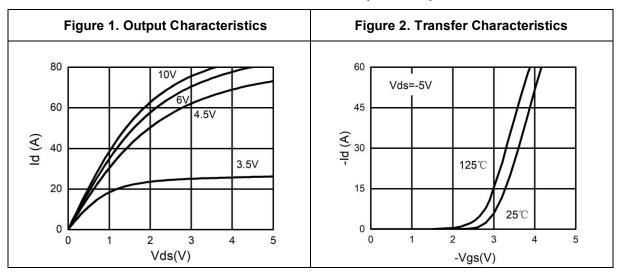
Electrical Characteristics (T_J=25℃ unless otherwise noted)

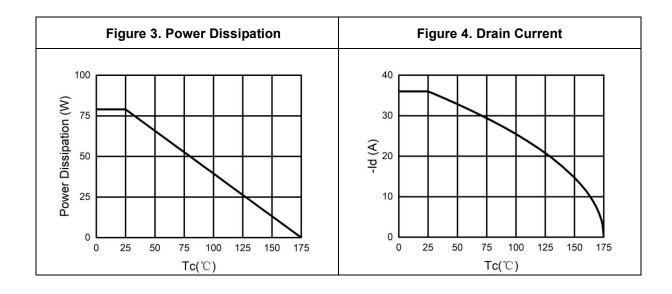
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
On/Off States						
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V I _D =-250μA	-60			V
IDSS	Zero Gate Voltage Drain Current	V _{DS} =-60V, V _{GS} =0V			-1	μΑ
Igss	Gate-Body Leakage Current	V _{GS} =±20V, V _{DS} =0V			±100	nA
$V_{GS(th)}$	Gate Threshold Voltage	V _{DS} =V _{GS} , I _D =-250μA	-1	-1.8	-2.5	V
g FS	Forward Transconductance	V _{DS} =-5V, I _D =-15A		35		S
D.	Drain-Source On-State Resistance	V _{GS} =-10V, I _D =-15A		29	33	mΩ
Rds(on)		V _{GS} =-4.5V, I _D =-10A		35	46	mΩ
Dynamic Chara	acteristics		•			
Ciss	Input Capacitance			4026		pF
Coss	Output Capacitance	V _{DS} =-25V, V _{GS} =0V, f=1.0MHz		134		pF
Crss	Reverse Transfer Capacitance			98		pF
Switching Para	meters		I	1		
t _{d(on)}	Turn-on Delay Time			12.2		nS
tr	Turn-on Rise Time	V_{GS} =-10V, V_{DS} =-30V, R_{L} =1.5 Ω , R_{GEN} =3 Ω		10		nS
$t_{d(off)}$	Turn-Off Delay Time			64		nS
t _f	Turn-Off Fall Time			14		nS
Qg	Total Gate Charge			68		nC
Qgs	Gate-Source Charge	V _{GS} =-10V, V _{DS} =-30V, I _D =-20A		10.5		nC
Q_{gd}	Gate-Drain Charge			13		nC
Source-Drain D	Diode Characteristics					1
I _{SD}	Source-Drain Current (Body Diode)				30	Α
V _{SD}	Forward on Voltage (Note 3)	V _{GS} =0V, I _S =-15A	-15A		-1.2	V
t _{rr}	Reverse Recovery Time	I _F =-20A, di/dt=100A/μs	:=-20A, di/dt=100A/μs 26			ns
Qrr	Reverse Recovery Charge	I _F =-20A, di/dt=100A/μs		29		nC

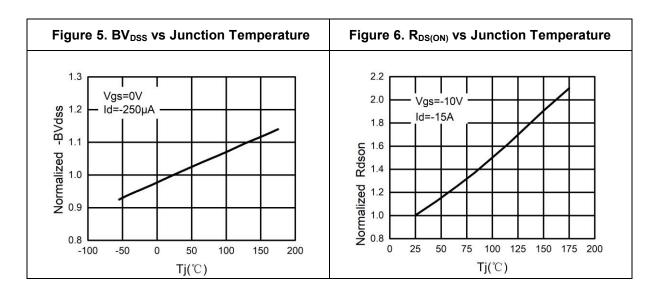
Notes 1.Repetitive Rating: Pulse width limited by maximum junction temperature. Notes 2.E_{AS} condition: T_J =25°C, V_{DD} =40V, V_G =-10V, Rg=25 Ω , L=0.5mH. Notes 3.Repetitive Rating: Pulse width limited by maximum junction temperature.



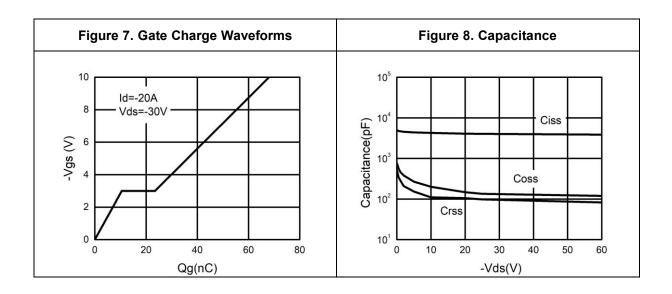
Typical Electrical And Thermal Characteristics (Curves)

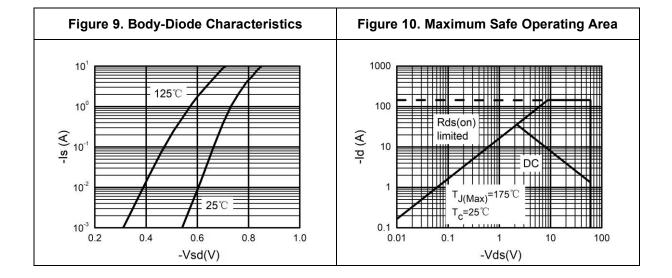






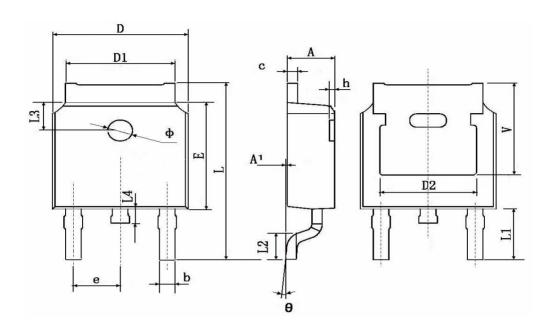








TO252-2L Package Information



Symbol	Dimensions In Millimeters		Dimensions In Inches		
	Min.	Max.	Min.	Max.	
А	2.200	2.400	0.087	0.094	
A1	0.000	0.127	0.000	0.005	
b	0.660	0.860	0.026	0.034	
С	0.460	0.580	0.018	0.023	
D	6.500	6.700	0.256	0.264	
D1	5.100	5.460	0.201	0.215	
D2	4.830 TYP.		0.190 TYP.		
E	6.000	6.200	0.236	0.244	
е	2.186	2.386	0.086	0.094	
L	9.800	10.400	0.386	0.409	
L1	2.900 TYP.		0.114 TYP.		
L2	1.400	1.700	0.055	0.067	
L3	1.600 TYP.		0.063 TYP.		
L4	0.600	1.000	0.024	0.039	
Ф	1.100	1.300	0.043	0.051	
θ	0°	8°	0°	8°	
h	0.000	0.300	0.000	0.012	
V	5.350	TYP.	0.211 TYP.		



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